

Supporting Information

“Double-Sided Tape” Modifier Bridging TiO₂/Perovskite Buried Interface for Efficient and Stable All-Inorganic Perovskite Solar Cells

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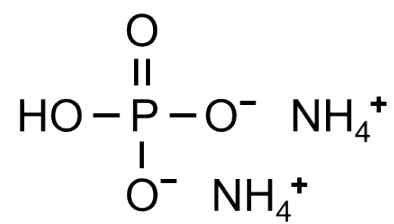


Fig. S1. The chemical structural formula of DAP.

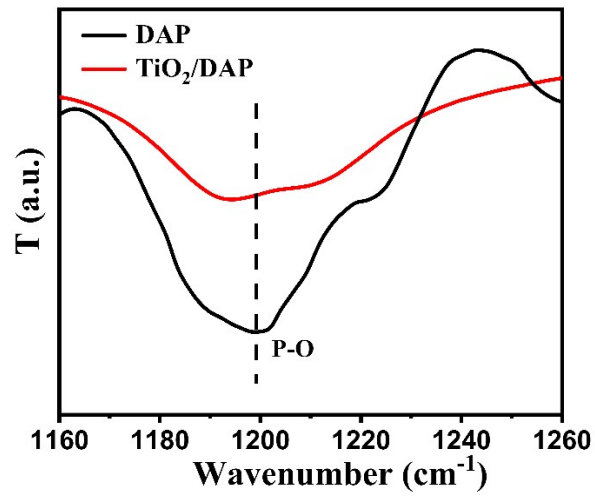


Fig. S2. FTIR spectra of P-O bond for DAP and TiO₂/DAP samples.

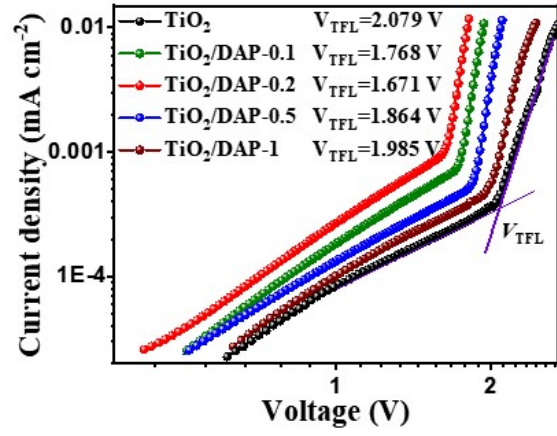


Fig. S3. The dark J - V curves of ETL-only devices with a structure of FTO/TiO₂/with and without DAP/Carbon.

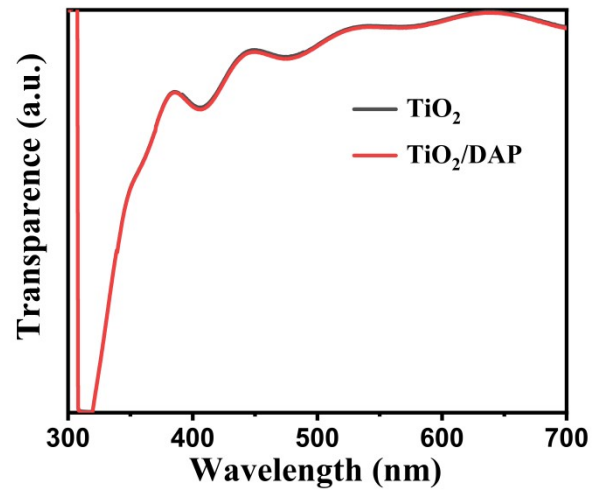


Fig. S4. The transmission spectra of TiO₂ and TiO₂/DAP films.

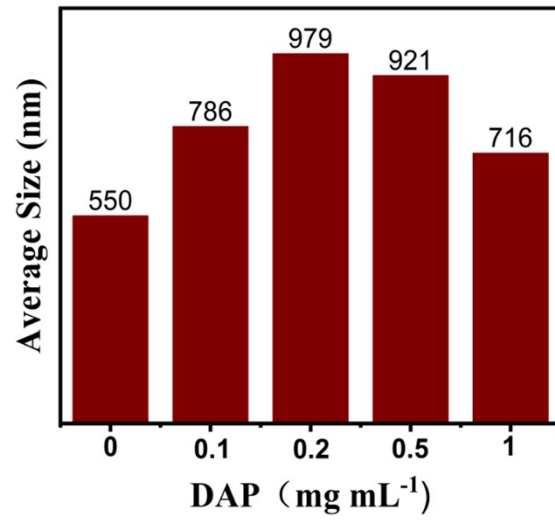


Fig. S5. The average grain size distribution statistical histogram of perovskite films deposited on various TiO₂ layers.

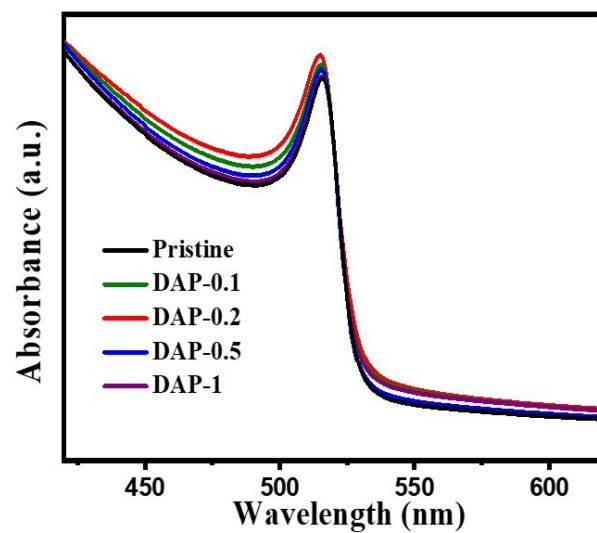


Fig. S6. UV-vis absorption spectrums of perovskite films deposited on various TiO₂

ETLs.

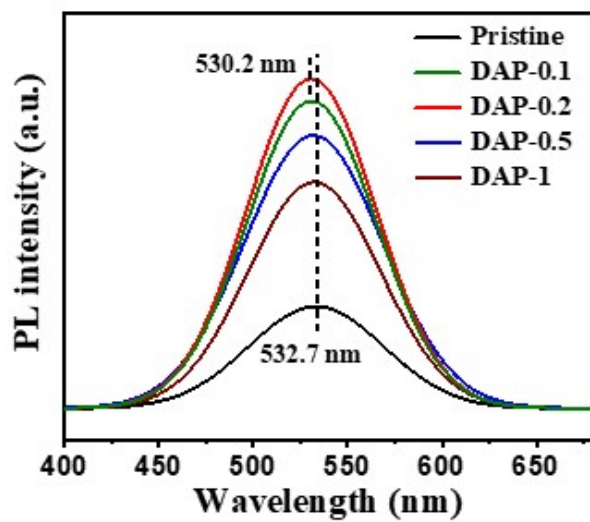


Fig. S7. The steady-state PL spectra excited from air side of perovskite films directly deposited on various glass substrates.

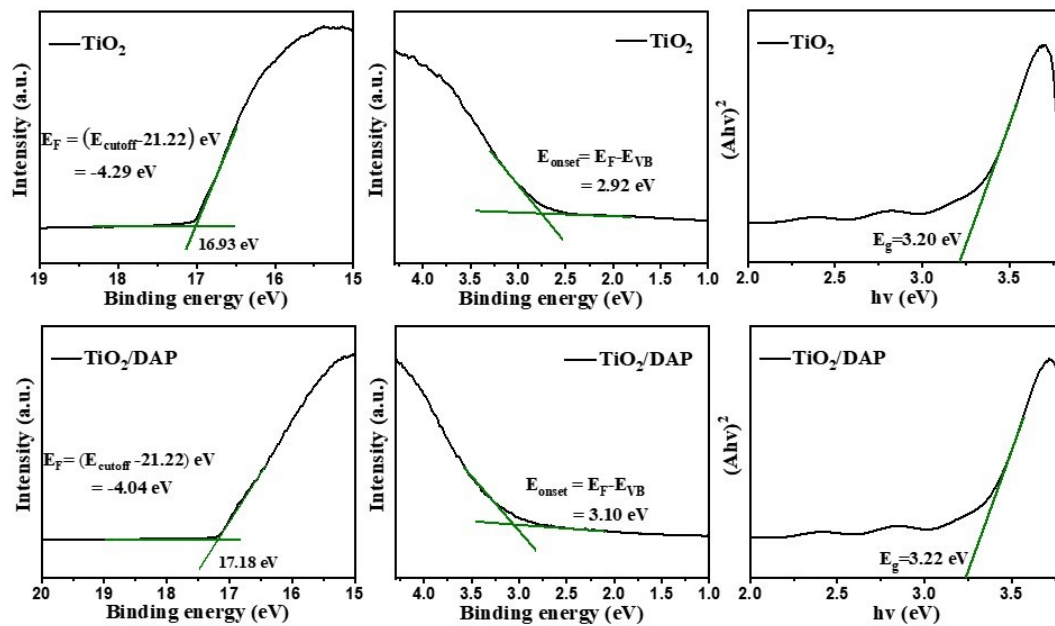


Fig. S8. Ultraviolet photoelectron spectra (UPS) and the curves of $(Ahv)^2$ as a function of $h\nu$ for various TiO₂ films.

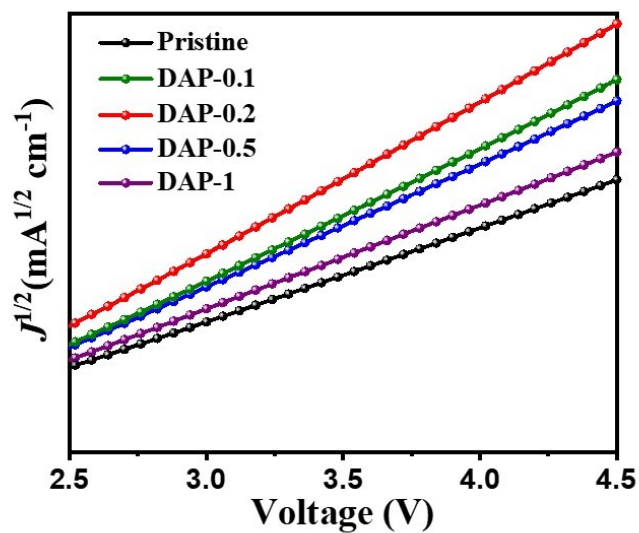


Fig. S9. The $J^{1/2}$ - V curves of electron-only devices with a structure of FTO/TiO₂/without or with DAP/perovskite/PCBM/carbon.

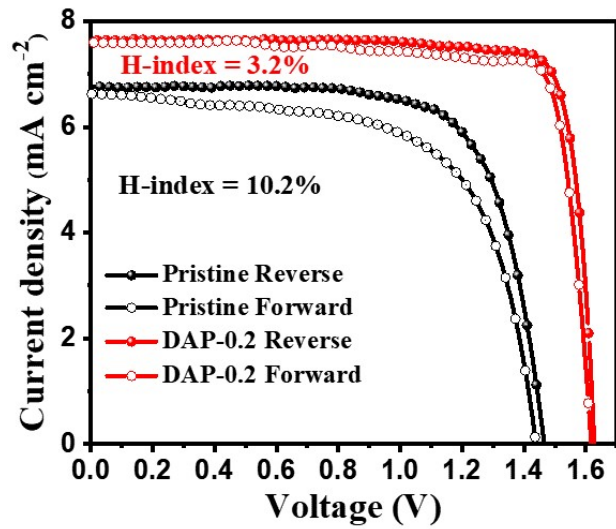


Fig. S10. The J - V curves under forward and reverse scan directions of the control and optimized PSCs.

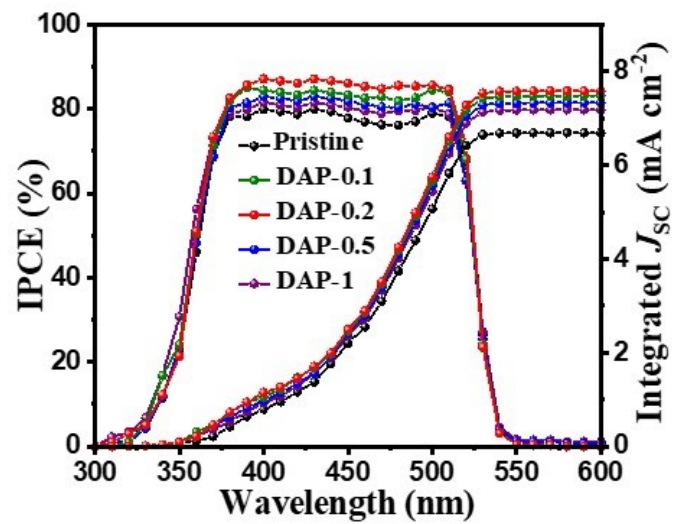


Fig. S11. IPCE spectra and integrated current density of various devices.

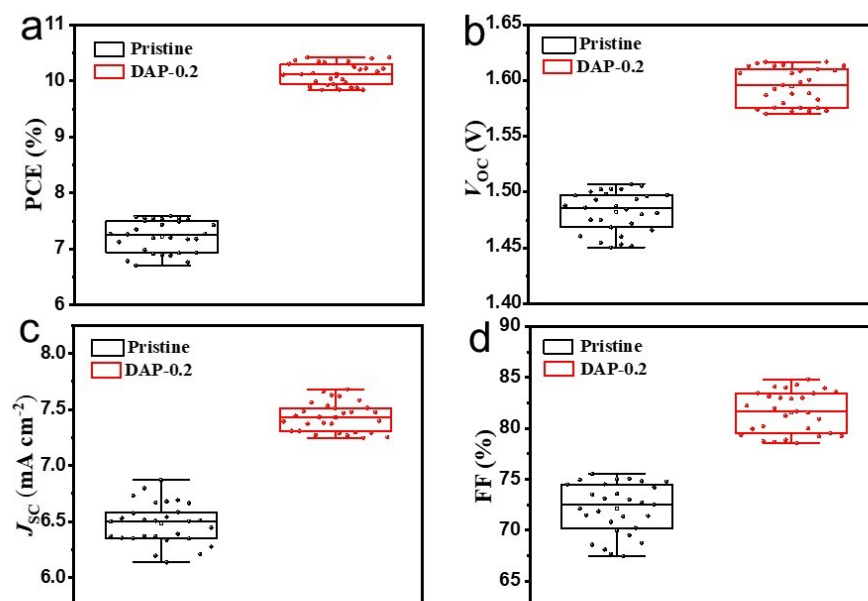


Fig. S12. Statistical distribution of (a) PCE, (b) V_{oc} , (c) J_{sc} and (d) FF for thirty random control and optimized CsPbBr₃ PSCs.

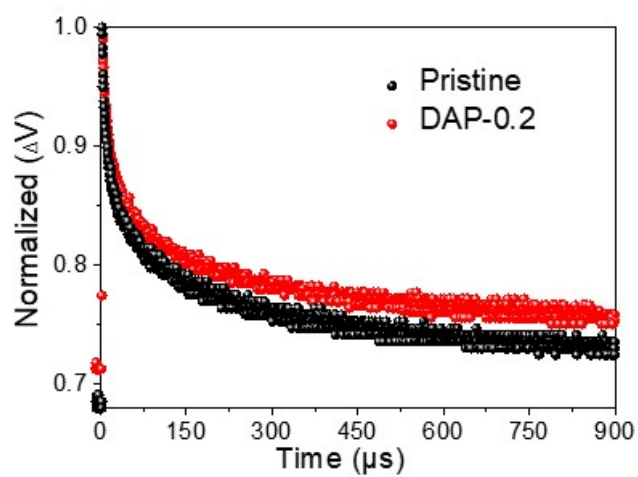


Fig. S13. TPV curves of various CsPbBr₃ PSCs under 0.3 sun illumination.

Table S1. The electron trap state density of TiO₂ films with and without DAP modification.

Samples	V_{TFL} (V)	N_{t} (10^{17} cm ⁻³)
Pristine	2.079	5.69
DAP-0.1	1.768	4.76
DAP-0.2	1.671	4.52
DAP-0.5	1.864	5.01
DAP-1	1.985	5.37

Table S2. The electron trap state density and electron mobility of CsPbBr₃ films deposited on various TiO₂ ETLs.

Samples	V_{TFL} (V)	N_t (10^{16} cm ⁻³)	μ_e (10^{-4} cm ² V ⁻¹ s ⁻²)
Pristine	1.635	2.06	4.52
DAP-0.1	1.356	1.71	8.41
DAP-0.2	1.291	1.62	11.7
DAP-0.5	1.444	1.83	7.12
DAP-1	1.541	1.95	5.48

Table S3. Summary of the parameters of CsPbBr₃ PSCs with champion PCE.

Devices	J_{sc} (mA cm ⁻²)	V_{oc} (V)	FF (%)	PCE (%)	Ref.
FTO/c-TiO ₂ /m-TiO ₂ /DAP/CsPbBr ₃ /Carbon	7.57	1.621	84.05	10.31	This work
FTO/c-TiO ₂ /m-TiO ₂ /CsPbBr ₃ / Carbon	7.40	1.220	84.10	7.37	1
FTO/c-TiO ₂ /m-TiO ₂ /GQDs/CsPbBr ₃ /Carbon	8.12	1.458	82.1	9.72	2
FTO/TiO ₂ /CsPbBr ₃ /SiQDs/spiro-OMeTAD/Ag	7.80	1.420	75.00	8.31	3
TiO ₂ /CsPbBr ₃ /Cu(Cr,Ba)O ₂ NCs/Carbon	7.81	1.620	85.50	10.79	4
FTO/TiO ₂ /PTI-CsPbBr ₃ /spiro-OMeTAD/Ag	9.78	1.490	74.47	10.91	5
FTO/c-TiO ₂ /CsPbBr ₃ /CsPbBr ₃ -CsPb ₂ Br ₅ /CsPbBr ₃ -Cs ₄ PbBr ₆ /Carbon	9.24	1.461	75.39	10.17	6
FTO/Sb-TiO ₂ /CsPbBr ₃ /Carbon	6.70	1.654	80.40	8.91	7
FTO/TiO ₂ -AC/CsPbBr ₃ /ZnPc/Carbon	7.64	1.606	82.47	10.12	8
FTO/L-TiO ₂ :MoSe ₂ /CsPbBr ₃ /Carbon	6.70	1.615	78.70	10.02	9
FTO/c-TiO ₂ /m-TiO ₂ /CsPbBr ₃ /Carbon	7.13	1.380	62.0	6.10	10
FTO/c-TiO ₂ /m-TiO ₂ /Sm ³⁺ -CsPbBr ₃ /Carbon	7.48	1.594	85.10	10.14	11

FTO/c-TiO ₂ /m-TiO ₂ /Sr ²⁺ -CsPbBr ₃ / Carbon	7.71	1.540	81.10	9.63	12
FTO/TiO ₂ /CQD-CsPbBr ₃ IO/Spiro- OMeTAD/Au	11.34	1.060	69.00	8.29	13
FTO/c-TiO ₂ /CsPbBr ₃ /Carbon	6.89	1.49	79.0	8.11	14
FTO/c-TiO ₂ /CsPbBr ₃ /Ti ₃ C ₂ -MXene/ Carbon	8.54	1.444	73.08	9.01	15
FTO/c-TiO ₂ /CsPbBr ₃ /spiro- OMeTAD/Au	5.60	1.500	62.00	5.40	16
FTO/c-TiO ₂ /m-TiO ₂ /CsPbBr ₃ +L- lysine/Carbon	7.64	1.565	81.0	9.68	17
FTO/c-TiO ₂ /m-TiO ₂ /Sn ²⁺ -CsPbBr ₃ / Carbon	7.66	1.370	82.22	8.63	18
FTO/TiO ₂ /CsPbBr ₃ /MnS/Carbon	8.28	1.520	83.00	10.45	19
FTO/c-TiO ₂ /m- TiO ₂ /CsPbBr ₃ /[BMMIm]Cl/Carbon	7.45	1.610	83.00	9.92	20

Table S4. The carrier lifetime parameters of perovskite films deposited on various TiO₂ ETLs.

Samples	τ_{ave} (ns)	τ_1 (ns)	A_1 (%)	τ_2 (ns)	A_2 (%)
Pristine	0.78	0.69	54.33	13.95	45.67
DAP-0.1	0.26	0.37	62.85	7.63	37.15
DAP-0.2	0.15	0.22	61.92	5.31	38.08
DAP-0.5	0.34	0.45	63.36	8.74	36.64
DAP-1	0.52	0.61	64.18	10.96	35.82

The TRPL attenuation curve is fitted with a double exponential decay function: $I = A_1 e^{-(\tau_1 - \tau_0)/\tau_1} + A_2 e^{-(\tau_1 - \tau_0)/\tau_2}$ to obtain the carrier lifetime, where τ_1 represents the faster defect-related non-radiation recombination, τ_2 represents the slower radiation recombination part.²¹ Through the following formula: $\tau_{\text{ave}} = (A_1 \tau_1^2 + A_2 \tau_2^2) / (A_1 \tau_1 + A_2 \tau_2)$, the average lifetime (τ_{ave}) of photogenerated carriers can be obtained.

Table S5. EIS parameters of CsPbBr₃ PSCs with and without DAP modifier.

Devices	R_s (Ω cm ²)	R_{rec} (Ω cm ²)
Pristine	16.37	52.71
DAP-0.1	11.02	91.23
DAP-0.2	6.94	109.82
DAP-0.5	14.06	81.26
DAP-1	14.80	72.83

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